NSN 5961-00-469-8159

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-469-8159 **Inclosure Material:** Metal **Overall Length:** Between 0.150 inches and 0.180 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **End Application:** P-3 acft **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 75.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, instantaneous all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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